

JFW



PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Docket No: Q66212

KIYOKU, HIROYUKI, et al.

Appln. No.: 09/986,332

Group Art Unit: 1765

Confirmation No.: 5542

Examiner: Matthew A. ANDERSON

Filed: November 08, 2001

For: NITRIDE SEMICONDUCTOR GROWTH METHOD, NITRIDE SEMICONDUCTOR
SUBSTRATE, AND NITRIDE SEMICONDUCTOR DEVICE

AMENDMENT UNDER 37 C.F.R. § 1.111

MAIL STOP AMENDMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

In response to the Office Action dated June 16, 2004, please amend the above-identified
application as follows on the accompanying pages.

TABLE OF CONTENTS

AMENDMENTS TO THE CLAIMS	2
REMARKS.....	13